

High speed switching transistor (60V, 5A)

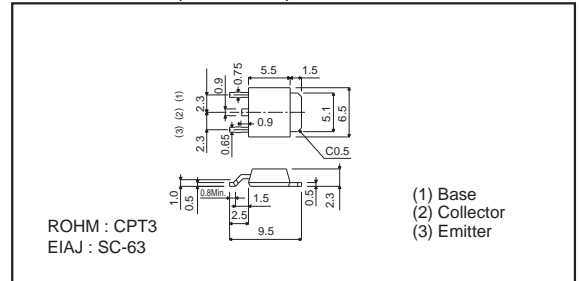
2SC5103
●Features

- 1) Low $V_{CE(sat)}$ (Typ. 0.15V at $I_c / I_B = 3 / 0.15A$)
- 2) High speed switching (t_f : Typ. 0.1 μs at $I_c = 3A$)
- 3) Wide SOA. (safe operating area)
- 4) Complements the 2SA1952.

●Absolute maximum ratings (Ta=25°C)

Parameter	Symbol	Limits	Unit
Collector-base voltage	V_{CBO}	100	V
Collector-emitter voltage	V_{CEO}	60	V
Emitter-base voltage	V_{EBO}	5	V
Collector current	I_c	5	A(DC)
		10	A(Pulse) *
Collector power dissipation	P_c	1	W
		10	W(Tc=25°C)
Junction temperature	T_j	150	°C
Storage temperature	T_{stg}	-55 to +150	°C

*Single pulse Pw=100ms

●Dimensions (Unit : mm)

●Packaging specifications and hFE

Type	2SC5103
Package	CPT3
hFE	Q
Code	TL
Basic ordering unit (pieces)	2500

●Electrical characteristics (Ta=25°C)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Collector-base breakdown voltage	BV_{CBO}	100	-	-	V	$I_c = 50\mu A$
Collector-emitter breakdown voltage	BV_{CEO}	60	-	-	V	$I_c = 1mA$
Emitter-base breakdown voltage	BV_{EBO}	5	-	-	V	$I_E = 50\mu A$
Collector cutoff current	I_{CBO}	-	-	10	μA	$V_{CB} = 100V$
Emitter cutoff current	I_{EBO}	-	-	10	μA	$V_{EB} = 5V$
Collector-emitter saturation voltage	$V_{CE(sat)}$	-	0.15	0.3	V	$I_c/I_B = 3A/0.15A$ *
		-	-	0.5	V	$I_c/I_B = 4A/0.2A$ *
Base-emitter saturation voltage	$V_{BE(sat)}$	-	-	1.2	V	$I_c/I_B = 3A/0.15A$ *
		-	-	1.5	V	$I_c/I_B = 4A/0.2A$ *
DC current transfer ratio	h_{FE}	120	-	270	-	$V_{CE}/I_c = 2V/1A$
		40	-	-	-	$V_{CE}/I_c = 2V/3A$
Transition frequency	f_T	-	120	-	MHz	$V_{CB} = 10V, I_E = -0.5A, f = 30MHz$
Output capacitance	C_{ob}	-	80	-	pF	$V_{CE} = 10V, I_E = 0A, f = 1MHz$ *
Turn-on time	t_{on}	-	-	0.3	μs	$I_c = 3A, R_L = 10\Omega$
Storage time	t_{stg}	-	-	1.5	μs	$I_{B1} = -I_{B2} = 0.15A$
Fall time	t_f	-	0.1	0.3	μs	$V_{CC} \approx 30V$

* Measured using pulse current.

●Electrical characteristics curves

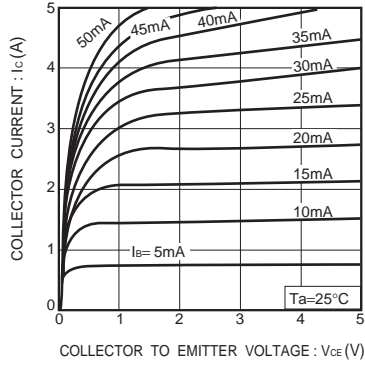


Fig.1 Ground emitter output characteristics

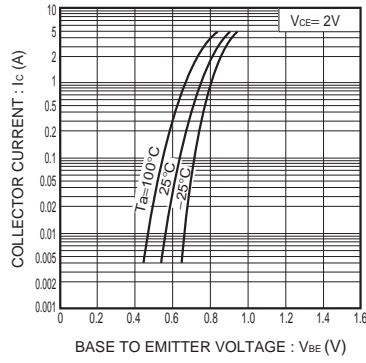


Fig.2 Ground emitter propagation characteristics

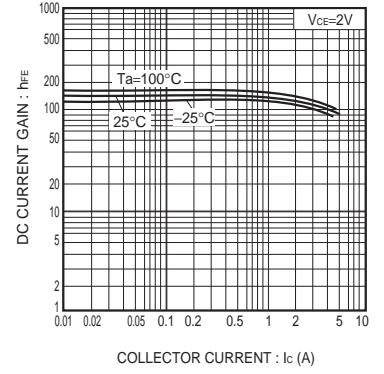


Fig.3 DC current gain vs. collector current

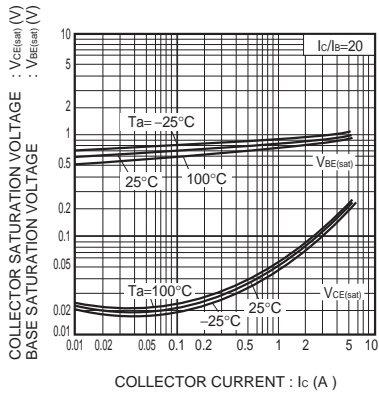


Fig.4 Collector-emitter saturation voltage
Base-emitter saturation voltage - collector current

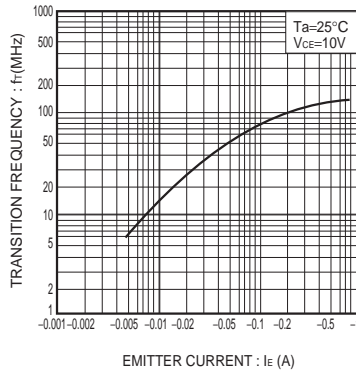


Fig.5 Gain bandwidth product vs. emitter current

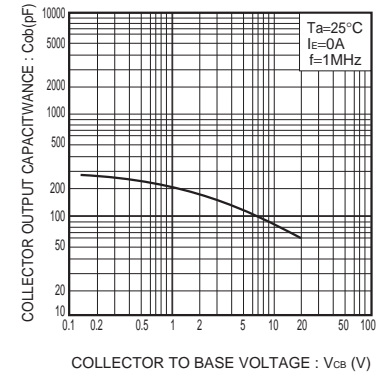


Fig.6 Collector output capacitance vs. collector-base voltage

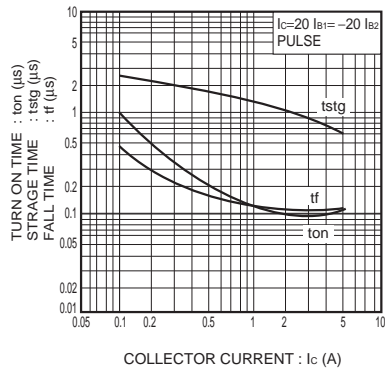


Fig.7 Switching characteristics

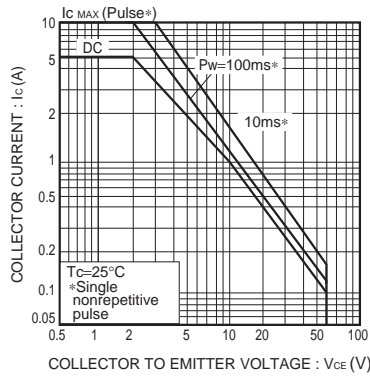


Fig.8 Safe operating area

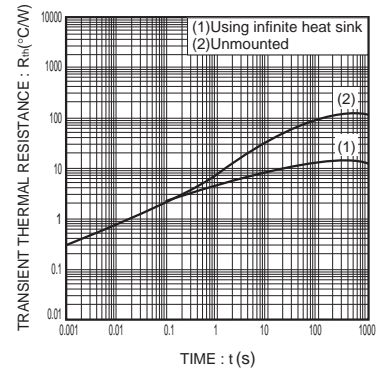


Fig.9 Transient thermal resistance

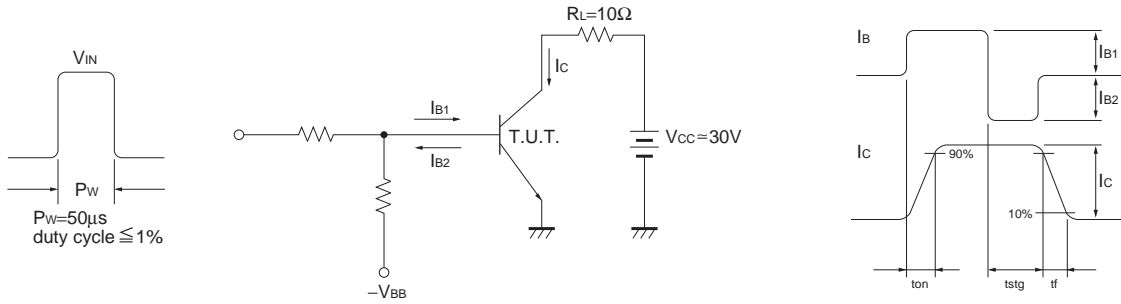


Fig.10 Switching characteristic circuit

Notes

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